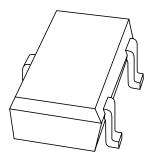
# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# PMST2369 NPN switching transistor

Product data sheet Supersedes data of 1997 May 05 1999 Apr 22



# **NPN** switching transistor

**PMST2369** 

#### **FEATURES**

- Low current (max. 200 mA)
- Low voltage (max. 15 V).

#### **APPLICATIONS**

 High-speed switching applications, primarily in portable and consumer equipment.

#### **DESCRIPTION**

NPN switching transistor in a SOT323 plastic package.

#### **MARKING**

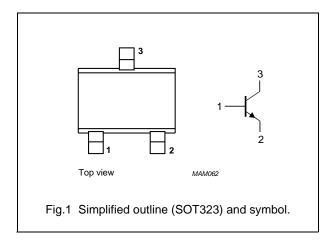
TYPE NUMBER	MARKING CODE <sup>(1)</sup>		
PMST2369	*1J		

#### Note

\* = - : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	40	V
$V_{CEO}$	collector-emitter voltage	open base	_	15	V
$V_{EBO}$	emitter-base voltage	open collector	_	5	V
I <sub>C</sub>	collector current (DC)		_	200	mA
I <sub>CM</sub>	peak collector current	$t_p \le 10 \ \mu s$	_	300	mA
I <sub>BM</sub>	peak base current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	625	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub> collector cut-off current I		I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V	_	400	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V; T <sub>j</sub> = 125 °C	_	30	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 4 V	_	100	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 1 V	40	120	
		$I_C = 10 \text{ mA}; V_{CE} = 1 \text{ V}; T_{amb} = -55 ^{\circ}\text{C}$	20	_	
		I <sub>C</sub> = 100 mA; V <sub>CE</sub> = 2 V; note 1	20	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	_	250	mV
V <sub>BEsat</sub> base-emitter saturation voltage		I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	700	850	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 5$ V; $f = 1$ MHz	_	4	pF
f <sub>T</sub> transition frequency		$I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	500	_	MHz
Switching t	imes (between 10% and 90% levels	s); (see Fig.2)			
t <sub>on</sub>	turn-on time	I <sub>Con</sub> = 10 mA; I <sub>Bon</sub> = 3 mA;	_	10	ns
t <sub>d</sub>	delay time	$I_{Boff} = -1.5 \text{ mA}$	_	4	ns
t <sub>r</sub>	rise time		_	6	ns
t <sub>off</sub>	turn-off time		_	20	ns
t <sub>s</sub>	storage time		_	10	ns
t <sub>f</sub>	fall time		_	10	ns

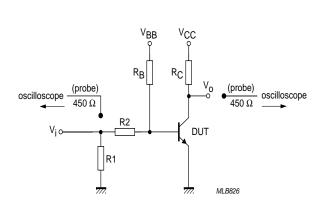
#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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$$\begin{split} &V_i=0.5~V~to~4.2~V;~T=500~\mu s;~t_p=10~\mu s;~t_r=t_f\leq 1~ns.\\ &R1=56~\Omega;~R2=1~k\Omega;~R_B=1~k\Omega;~R_C=270~\Omega.\\ &V_{BB}=0.2~V;~V_{CC}=2.7~V. \end{split}$$

Oscilloscope: input impedance  $Z_i = 50 \Omega$ .

Fig.2 Test circuit for switching times.

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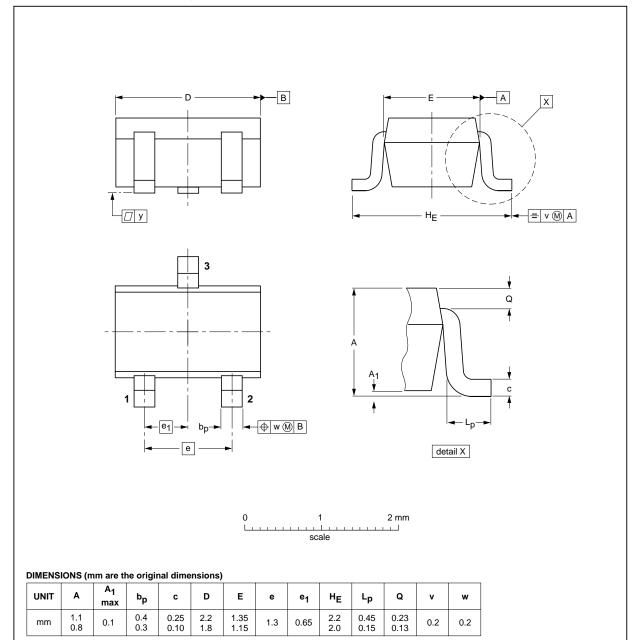
# NPN switching transistor

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#### **PACKAGE OUTLINE**

#### Plastic surface mounted package; 3 leads

**SOT323** 



OUTLINE		REFERENCES EURO			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT323			SC-70			97-02-28

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### NPN switching transistor

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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